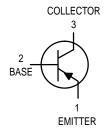
One Watt High Current Transistors

PNP Silicon



MPSW51 MPSW51A*

*Motorola Preferred Device



MAXIMUM RATINGS

Rating		Symbol	Value	Unit
Collector-Emitter Voltage	MPSW51 MPSW51A	VCEO	-30 -40	Vdc
Collector-Base Voltage	MPSW51 MPSW51A	VCBO	-40 -50	Vdc
Emitter-Base Voltage		VEBO	-5.0	Vdc
Collector Current — Continuous		IC	-1000	mAdc
Total Device Dissipation @ T _A = 25°C Derate above 25°C		PD	1.0 8.0	Watts mW/°C
Total Device Dissipation @ T _C = 25°C Derate above 25°C		PD	2.5 20	Watts mW/°C
Operating and Storage Junction Temperature Range		T _J , T _{Stg}	-55 to +150	°C

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{ heta JA}$	125	°C/W
Thermal Resistance, Junction to Case	R ₀ JC	50	°C/W

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Max	Unit
OFF CHARACTERISTICS				•	•
Collector-Emitter Breakdown Voltage ⁽¹⁾ (IC = -1.0 mAdc, I _B = 0)	MPSW51 MPSW51A	V(BR)CEO	-30 -40	_ _	Vdc
Collector-Base Breakdown Voltage (IC = -100 μAdc, IE = 0)	MPSW51 MPSW51A	V(BR)CBO	-40 -50	_	Vdc
Emitter-Base Breakdown Voltage (I _E = -100 μAdc, I _C = 0)		V(BR)EBO	-5.0	_	Vdc
Collector Cutoff Current $(V_{CB} = -30 \text{ Vdc}, I_{E} = 0)$ $(V_{CB} = -40 \text{ Vdc}, I_{E} = 0)$	MPSW51 MPSW51A	ІСВО	_ _	-0.1 -0.1	μAdc
Emitter Cutoff Current (VEB = -3.0 Vdc, IC = 0)		IEBO		-0.1	μAdc

^{1.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

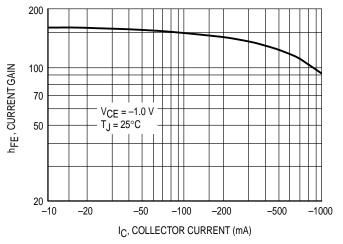
Preferred devices are Motorola recommended choices for future use and best overall value.



MPSW51 MPSW51A

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted) (Continued)

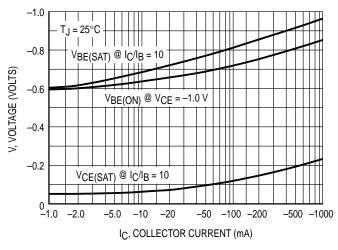
Characteristic	Symbol	Min	Max	Unit
ON CHARACTERISTICS	•	•	•	
DC Current Gain $ \begin{array}{l} (I_C = -10 \text{ mAdc, } V_{CE} = -1.0 \text{ Vdc)} \\ (I_C = -100 \text{ mAdc, } V_{CE} = -1.0 \text{ Vdc)} \\ (I_C = -1000 \text{ mAdc, } V_{CE} = -1.0 \text{ Vdc)} \end{array} $	hFE	55 60 50	_ _ _	_
Collector-Emitter Saturation Voltage (IC = -1000 mAdc, I _B = -100 mAdc)	VCE(sat)	_	-0.7	Vdc
Base-Emitter On Voltage (I _C = -1000 mAdc, V _{CE} = -1.0 Vdc)	VBE(on)	_	-1.2	Vdc
SMALL-SIGNAL CHARACTERISTICS				
Current–Gain – Bandwidth Product (I _C = –50 mAdc, V _{CE} = –10 Vdc, f = 20 MHz)	fT	50	_	MHz
Output Capacitance (V _{CB} = -10 Vdc, I _E = 0, f = 1.0 MHz)	C _{obo}	_	30	pF



V_{CE}, COLLECTOR VOLTAGE (VOLTS) IC = IC = IC = -1000 mA IC = IC = IC = -0.8 -100 -500 mA -50 mA –10 mA $\mathsf{m}\mathsf{A}$ -0.6 -0.4 -0.2 -0.01 - 0.02 - 0.05 - 0.1 - 0.2 - 0.5 - 1.0 - 2.0 - 5.0 - 10 - 20IB, BASE CURRENT (mA)

Figure 1. DC Current Gain

Figure 2. Collector Saturation Region



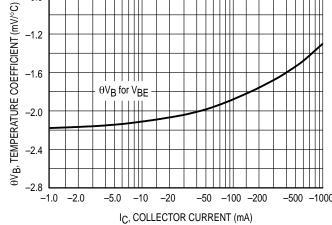
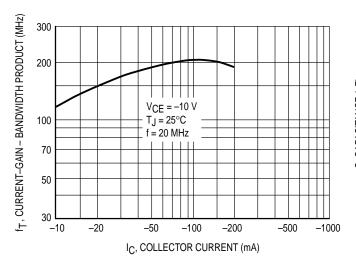


Figure 3. "ON" Voltages

Figure 4. Temperature Coefficient



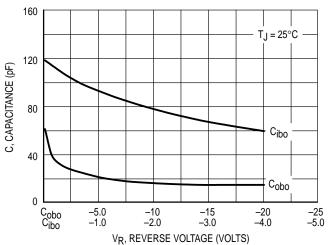


Figure 5. Current Gain — Bandwidth Product

Figure 6. Capacitance

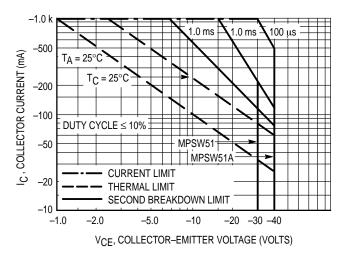
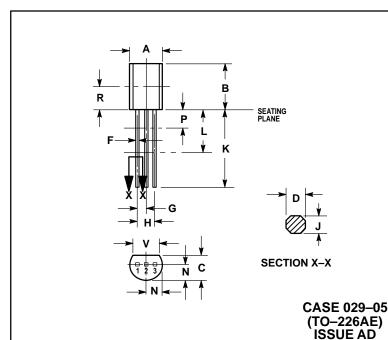


Figure 7. Active Region — Safe Operating Area

PACKAGE DIMENSIONS



- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
- 3. CONTOUR OF PACKAGE BEYOND DIMENSION R
- IS UNCONTROLLED.

 4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSIONS D AND J APPLY BETWEEN L AND K
 MIMIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.44	5.21
В	0.290	0.310	7.37	7.87
С	0.125	0.165	3.18	4.19
D	0.018	0.022	0.46	0.56
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.018	0.024	0.46	0.61
K	0.500		12.70	
L	0.250		6.35	_
N	0.080	0.105	2.04	2.66
Р	_	0.100		2.54
R	0.135		3.43	
V	0.135		3.43	

STYLE 1:

PIN 1. EMITTER BASE COLLECTOR

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